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FDPF33N25T N-Channel UniFETTM MOSFET 250 V, 33 A, 94 mΩ

Features

- $R_{DS(on)}$ = 94 m Ω (Max.) @ V_{GS} = 10 V, I_D = 16.5 A
- Low Gate Charge (Typ. 36.8 nC)
- Low C_{rss} (Typ. 39 pF)
- 100% Avalanche Tested

Applications

- PDP TV
- Lighting
- Uninterruptible Power Supply
- AC-DC Power Supply

August 2014

Description

UniFETTM MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.



Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol		Parameter	FDPF33N25T FDPF33N25TRDTU	Unit	
V _{DSS}	Drain-Source Voltage	250	V		
ID	Drain Current	- Continuous (T _C = 25°C) - Continuous (T _C = 100°C)	33* 20.4*	A A	
I _{DM}	Drain Current	- Pulsed (Note 1)	132*	Α	
V _{GSS}	Gate-Source voltage	± 30	V		
E _{AS}	Single Pulsed Avalance	che Energy (Note 2)	918	mJ	
I _{AR}	Avalanche Current	(Note 1)	33	Α	
E _{AR}	Repetitive Avalanche Energy		23.5	mJ	
dv/dt	Peak Diode Recovery	dv/dt (Note 3)	4.5	V/ns	
P _D	Power Dissipation	(T _C = 25°C) - Derate Above 25°C	37 0.29	W W/°C	
T _{J,} T _{STG}	Operating and Storag	-55 to +150	°C		
TL	Maximum Lead Tempe	300	°C		

*Drain current limited by maximum junction temperature.

Thermal Characteristics

Symbol	Parameter	FDPF33N25T FDPF33N25TRDTU	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction-to-Case, Max.	3.4	°C/W
R_{\thetaJA}	Thermal Resistance, Junction-to-Ambient, Max.	62.5	0/11

Package Marking and Ordering Information	Package	Marking	and	Ordering	Information
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Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDPF33N25T	FDPF33N25T	TO-220F	Tube	N/A	N/A	50 units
FDPF33N25TRDTU	FDPF33N25T	TO-220F (LG-formed)	Tube	N/A	N/A	50 units

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics					
BV _{DSS}	Drain-Source Breakdown Voltage	V_{GS} = 0 V, I_{D} = 250 μ A, T_{J} = 25°C				V
ΔBV_{DSS} / ΔT_{J}	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		0.25		V/∘C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 250 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = 200 \text{ V}, T_{C} = 125^{\circ}\text{C}$			1 10	μΑ μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30 V, V _{DS} = 0 V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = -30 V, V _{DS} = 0 V			-100	nA
On Charac	teristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$	3.0		5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10 V, I _D = 16.5 A		0.077	0.094	Ω
9 _{FS}	Forward Transconductance	V _{DS} = 40 V, I _D = 16.5 A		26.6		S
Dynamic C	Characteristics	•				
C _{iss}	Input Capacitance	V _{DS} = 25 V, V _{GS} = 0 V,		1640	2135	pF
C _{oss}	Output Capacitance	f = 1.0 MHz		330	430	pF
C _{rss}	Reverse Transfer Capacitance			39	59	pF
Switching	Characteristics					
t _{d(on)}	Turn-On Delay Time	V_{DD} = 125 V, I _D = 33 A, V_{GS} = 10 V, R _G = 25 Ω		35	80	ns
t _r	Turn-On Rise Time			230	470	ns
t _{d(off)}	Turn-Off Delay Time			75	160	ns
t _f	Turn-Off Fall Time	(Note 4)		120	250	ns
Qg	Total Gate Charge	V _{DS} = 200 V, I _D = 33 A,		36.8	48	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10 V (Note 4)		10		nC
Q _{gd}	Gate-Drain Charge			17		nC
Drain-Sou	rce Diode Characteristics and Maximur	n Ratings				
I _S	Maximum Continuous Drain-Source Diode Forward Current				33	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				132	Α
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = 33 A			1.4	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _S = 33 A,		220		ns
Q _{rr}	Reverse Recovery Charge	dI _F /dt =100 A/µs		1.71		μC

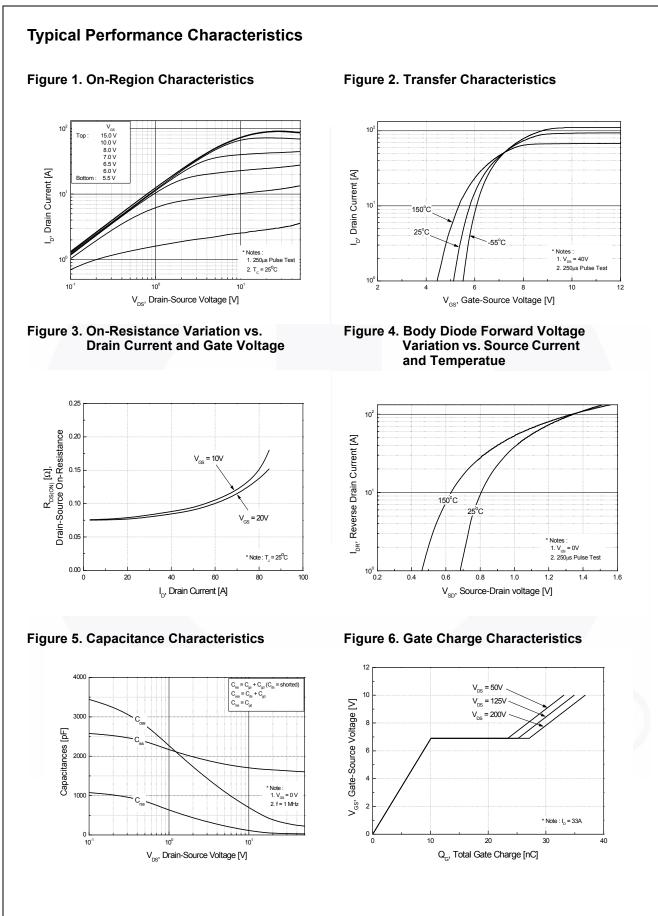
Notes:

1. Repetitive rating: pulse-width limited by maximum junction temperature.

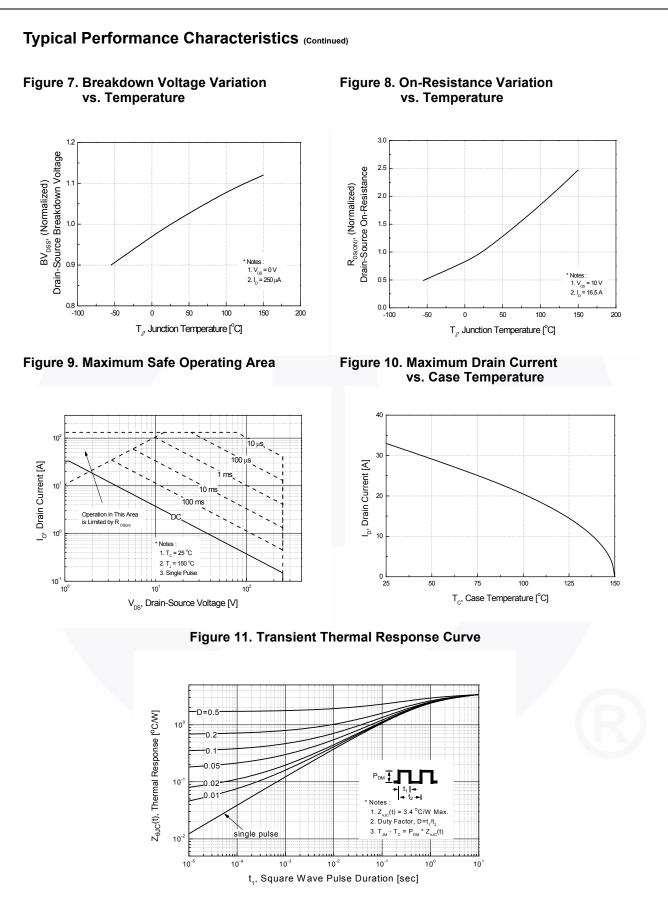
2. L = 1.35 mH, I_{AS} = 33 A, V_{DD} = 50 V, R_G = 25 $\Omega,$ starting T_J = 25°C.

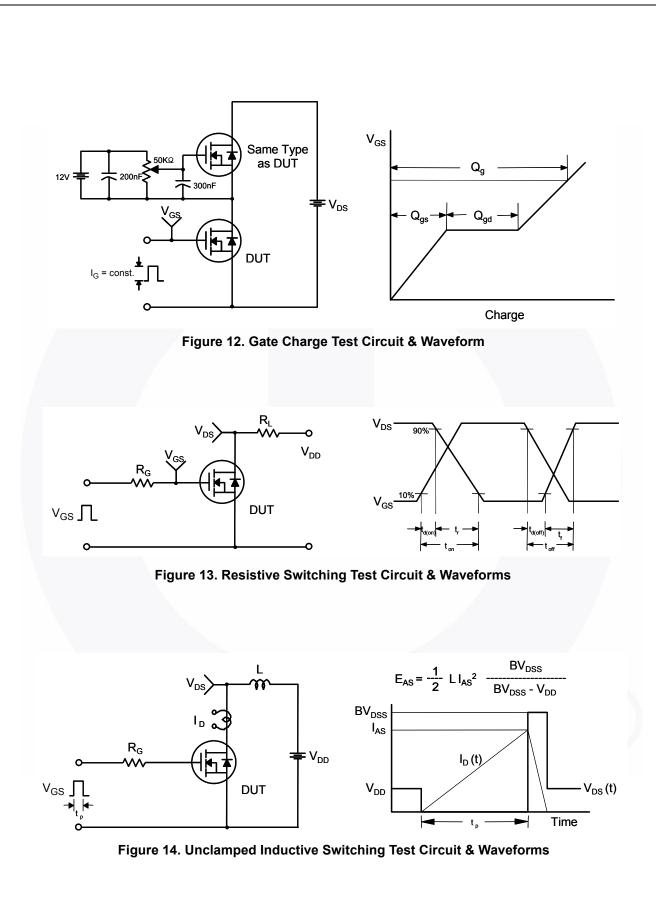
3. I_{SD} \leq 33 A, di/dt \leq 200 A/µs, V_{DD} \leq BV_{DSS}, starting T_J = 25°C.

4. Essentially independent of operating temperature typical characteristics.



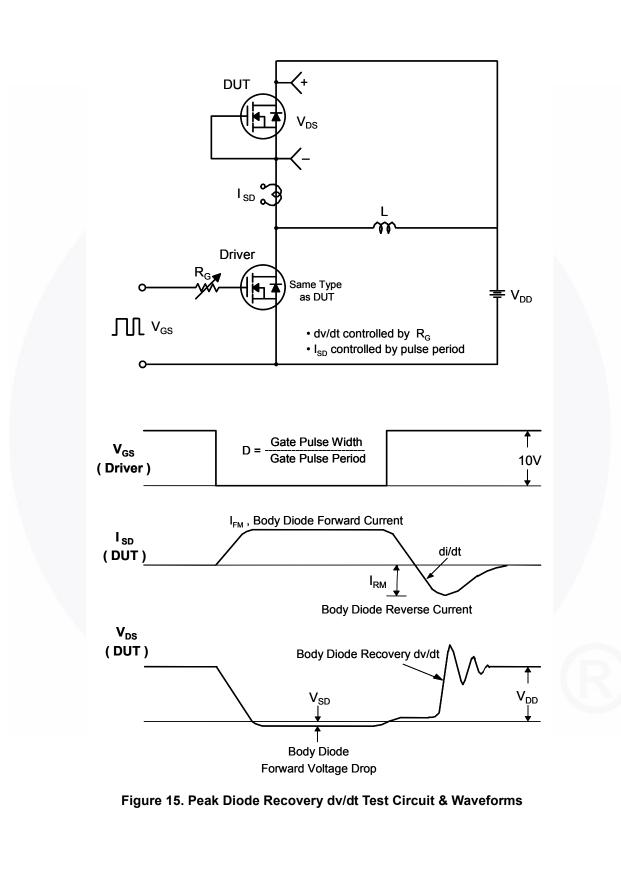
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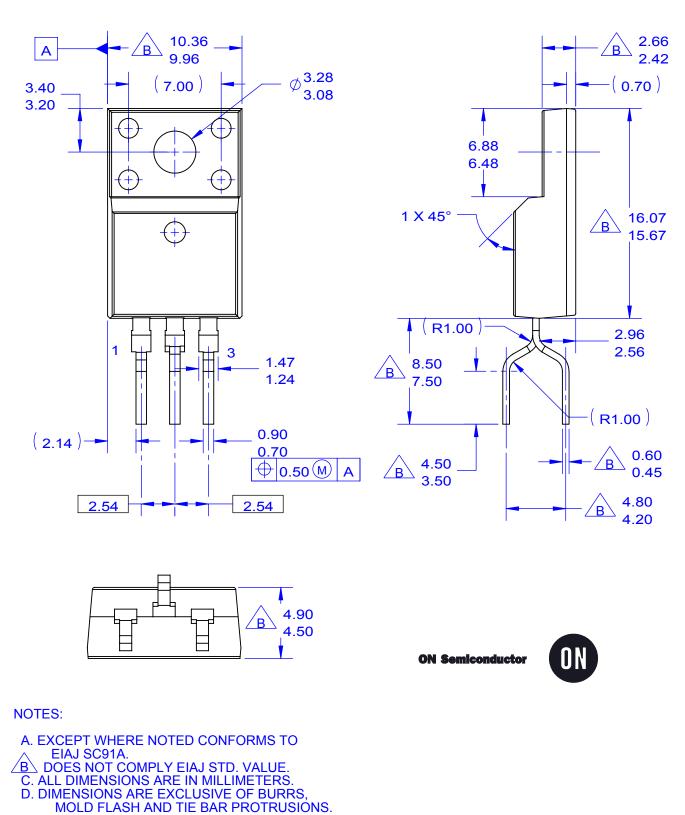




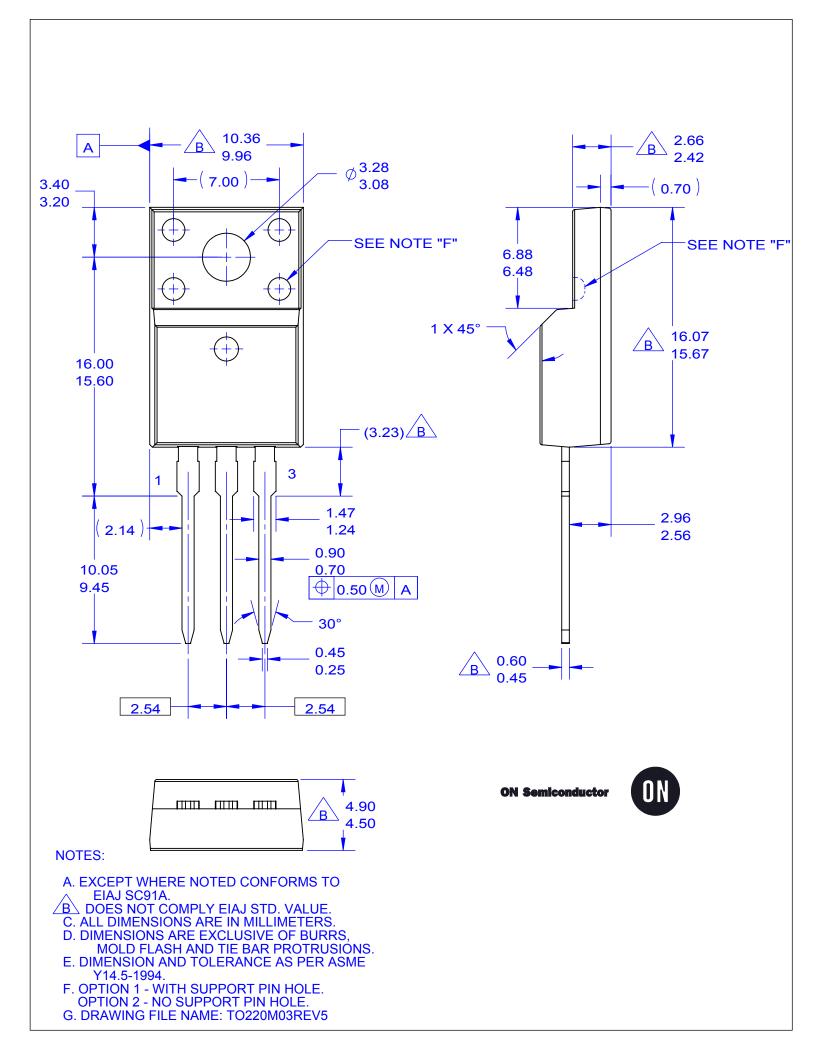
FDPF33N25T — N-Channel UniFETTM MOSFET

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- E. DIMENSION AND TOLERANCE AS PER ASME Y14.5-1994.
- F. DRAWING FILE NAME: TO220N03REV2



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